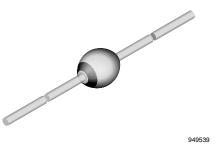
RoHS

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**Vishay Semiconductors** 

# **Standard Avalanche Sinterglass Diode**



MECHANICAL DATA

### Case: SOD-57

**Terminals:** plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: color band denotes cathode end

#### Mounting position: any

Weight: approx. 369 mg

#### FEATURES

- Glass passivated junction
- Hermetically sealed package
- Controlled avalanche characteristics
- Low reverse current
- Material categorization: COMPLIANT For definitions of compliance please see Www.vishay.com/doc?99912

## APPLICATIONS

• High voltage rectification diode

| ORDERING INFORMATION (Example) |               |   |        |  |  |
|--------------------------------|---------------|---|--------|--|--|
| DEVICE NAME                    | ORDERING CODE | CODE TAPED UNITS MINIMUM ORDER QUANTITY |        |  |  |
| BYT62                          | BYT62-TR      | 5000 per 10" tape and reel              | 25 000 |  |  |
| BYT62                          | BYT62-TAP     | 5000 per ammopack                       | 25 000 |  |  |

| PARTS TABLE |  |         |  |  |  |
|-------------|--|---------|--|--|--|
| PART        | TYPE DIFFERENTIATION                                 | PACKAGE |  |  |  |
| BYT62       | V <sub>R</sub> = 2400 V; I <sub>F(AV)</sub> = 350 mA | SOD-57  |  |  |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                           |               |      |  |
|--|--|---------------------------|---------------|------|--|
| PARAMETER  | TEST CONDITION                           | SYMBOL                    | VALUE         | UNIT |  |
| Reverse voltage = repetitive peak reverse voltage                                      | See electrical characteristics           | $V_{\rm R} = V_{\rm RRM}$ | 2400          | V    |  |
| Peak forward surge current   | t <sub>p</sub> = 10 ms, half sine wave   | I <sub>FSM</sub>          | 10            | А    |  |
| Average forward current  | $R_{thJA} \le 60 \text{ K/W}$            | I <sub>F(AV)</sub>        | 350           | mA   |  |
| Non repetitive reverse avalanche energy  | I <sub>(BR)R</sub> = 1 A, inductive load | E <sub>R</sub>            | 60            | mJ   |  |
| Junction temperature   |  | Tj                        | 175           | °C   |  |
| Storage temperature range  |  | T <sub>stg</sub>          | - 55 to + 190 | °C   |  |

| <b>MAXIMUM THERMAL RESISTANCE</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |       |      |  |
|--|---|-------------------|-------|------|--|
| PARAMETER  | TEST CONDITION                          | SYMBOL            | VALUE | UNIT |  |
| Junction ambient   | Lead length I = 10 mm, $T_L$ = constant | R <sub>thJA</sub> | 60    | K/W  |  |

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**BYT62** 



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                    |      |      |     |      |
|--|--|--------------------|------|------|-----|------|
| PARAMETER  | TEST CONDITION   | SYMBOL             | MIN. | TYP. | MAX | UNIT |
| Forward unlike a   | I <sub>F</sub> = 200 mA  | VF                 | -    | -    | 3   | V    |
|  | I <sub>F</sub> = 1 A   | VF                 | -    | -    | 3.6 | V    |
| Forward voltage  | I <sub>F</sub> = 1 A, T <sub>j</sub> = 175 °C                  | VF                 | -    | -    | 2.9 | V    |
|  | I <sub>F</sub> = 1 A, T <sub>j</sub> = - 40 °C                 | VF                 | -    | -    | 4   | V    |
| Reverse current  | $V_{R} = V_{RRM}$  | I <sub>R</sub>     | -    | -    | 5   | μA   |
|  | V <sub>R</sub> = V <sub>RRM</sub> , T <sub>j</sub> = 175 °C    | I <sub>R</sub>     | -    | -    | 250 | μA   |
|  | $V_{R} = V_{RRM}, T_{j} = -40 \text{ °C}$                      | I <sub>R</sub>     | -    | -    | 400 | nA   |
| Reverse breakdown voltage  | I <sub>R</sub> = 100 μA  | V <sub>(BR)R</sub> | 2500 | -    | -   | V    |
| Reverse recovery time  | $I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_R = 0.25 \text{ A}$ | t <sub>rr</sub>    | -    | -    | 5   | μs   |

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

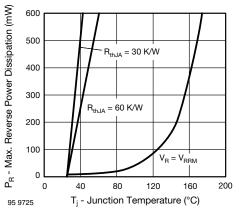


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

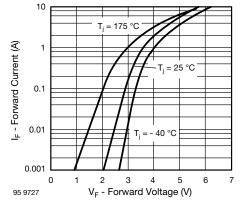


Fig. 3 - Max. Forward Current vs. Forward Voltage

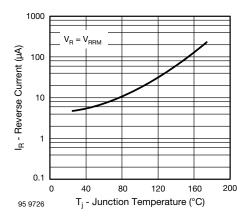


Fig. 2 - Max. Reverse Current vs. Junction Temperature

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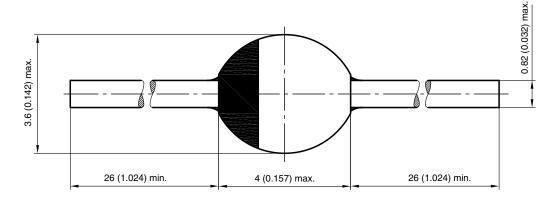
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#### PACKAGE DIMENSIONS in millimeters (inches): SOD-57



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